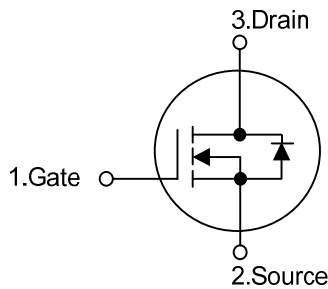


**BSS127****Power MOSFET****0.021A, 600V ENHANCEMENT
N-CHANNEL MOSFET****DESCRIPTION**

The UTC **BSS127** is an enhancement N-channel mode Power FET, it uses UTC's advanced technology to provide customers ultra high switching speed and ultra low gate charge.

FEATURES

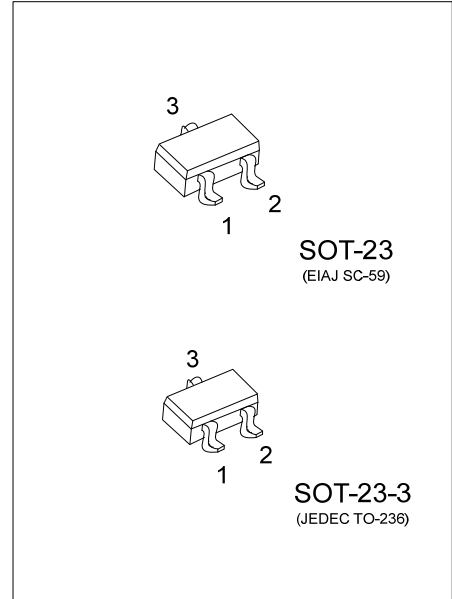
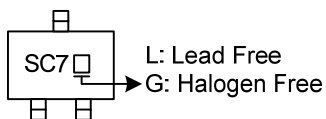
- * $R_{DS(ON)} \leq 600 \Omega$ @ $V_{GS}=4.5V$, $I_D=0.016A$
- * $R_{DS(ON)} \leq 500 \Omega$ @ $V_{GS}=10V$, $I_D=0.016A$
- * Ultra Low Gate Charge (Typical 140nC)
- * Ultra High Switching Speed

SYMBOL**ORDERING INFORMATION**

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
BSS127L-AE2-R	BSS127G-AE2-R	SOT-23-3	G	S	D	Tape Reel
BSS127L-AE3-R	BSS127G-AE3-R	SOT-23	G	S	D	Tape Reel

Note: Pin Assignment: G: Gate S: Source D: Drain

BSS127G-AE2-R (1) Packing Type (2) Package Type (3) Green Package	(1) R: Tape Real (2) AE2: SOT-23-3, AE3: SOT-23 (3) G: Halogen Free and Lead Free, L: Lead Free
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MARKING

■ ABSOLUTE MAXIMUM RATINGS (T_A=25°C, unless otherwise specified)

PARAMETER			SYMBOL	RATINGS	UNIT
Drain-Source Voltage			V _{DSS}	600	V
Gate-Source Voltage			V _{GSS}	±20	V
Drain Current	Continuous	T _A =25°C	I _D	0.021	A
		T _A =70°C		0.017	A
	Pulsed (T _A =25°C)		I _{DM}	0.09	A
Peak Diode Recovery dv/dt			dv/dt	6	kV/μs
Power Dissipation (T _A =25°C)			P _D	0.3	W
Junction Temperature			T _J	-55 ~ +150	°C
Storage Temperature Range			T _{STG}	-55 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

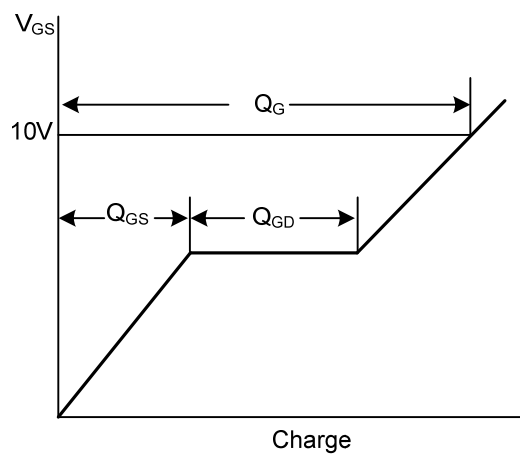
■ THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Ambient		θ _{JA}	325	°C/W

■ ELECTRICAL CHARACTERISTICS (T_J=25°C, unless otherwise specified)

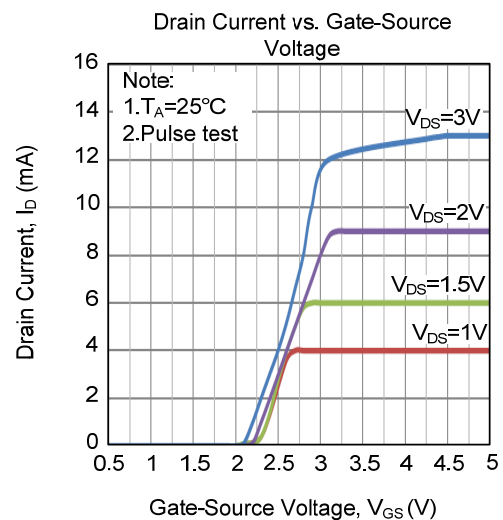
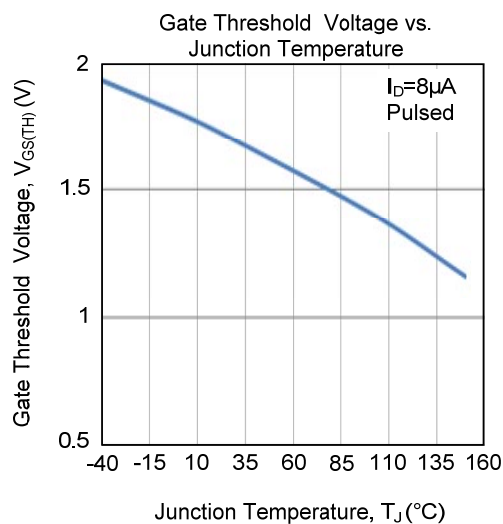
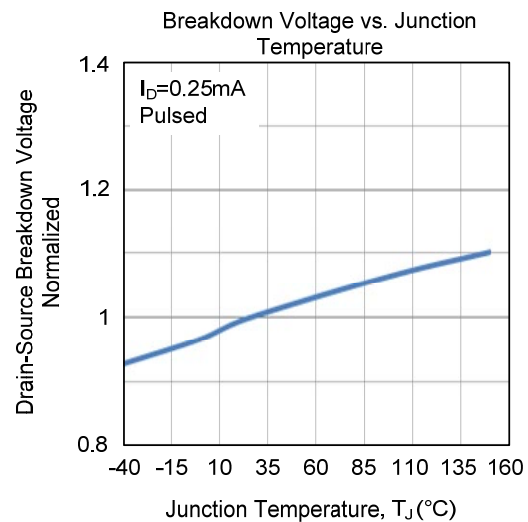
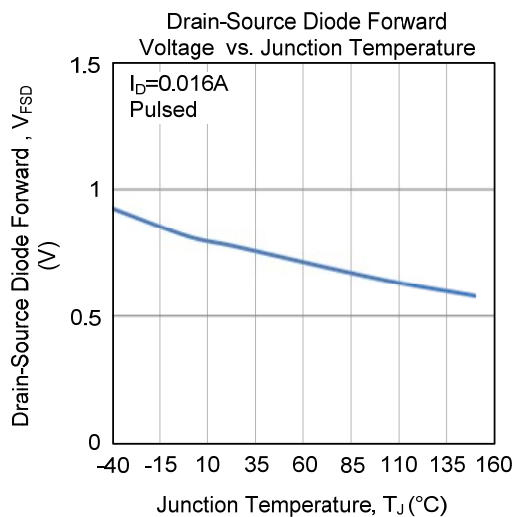
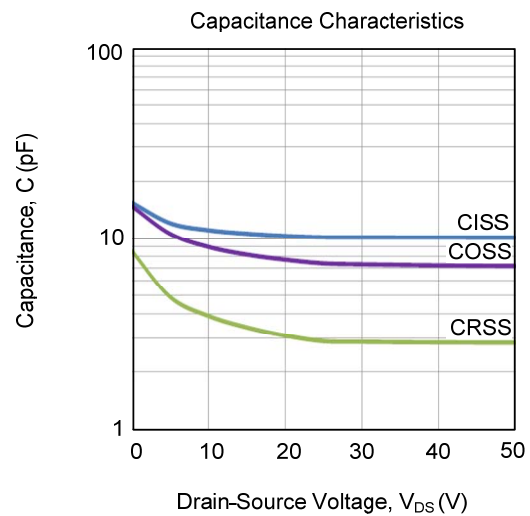
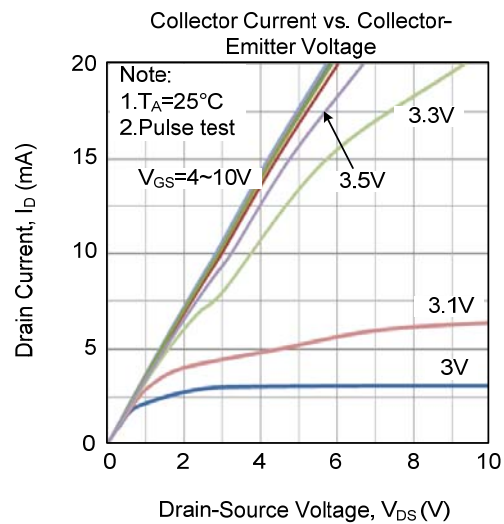
PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage		BV _{DSS}	I _D =250μA, V _{GS} =0V	600			V
Gate-Source Leakage Current	Forward	I _{GSS}	V _{GS} =+20V, V _{DS} =0V		+10	+100	nA
	Reverse		V _{GS} =-20V, V _{DS} =0V		-10	-100	nA
Drain-Source Leakage Current		I _{D(OFF)}	V _{GS} =0V, V _{DS} =600V, T _J =25°C			0.1	μA
			V _{GS} =0V, V _{DS} =600V, T _J =150°C			10	μA
ON CHARACTERISTICS							
Gate Threshold Voltage		V _{GS(TH)}	V _{DS} =V _{GS} , I _D =8μA	1.4	2.0	2.6	V
Static Drain-Source On-State Resistance		R _{DS(ON)}	V _{GS} =4.5V, I _D =0.016A		330	600	Ω
			V _{GS} =10V, I _D =0.016A		310	500	Ω
Forward Transconductance		g _{FS}	V _{DS} >2 I _D R _{DS(ON)MAX} , I _D =0.01A	0.007	0.015		S
DYNAMIC PARAMETERS							
Input Capacitance		C _{ISS}	V _{GS} =0V, V _{DS} =25V, f=1.0MHz		10		pF
Output Capacitance		C _{OSS}			7		pF
Reverse Transfer Capacitance		C _{RSS}			2.8		pF
SWITCHING PARAMETERS							
Total Gate Charge		Q _G	V _{GS} =0~10V, V _{DS} =300V, I _D =0.01A		0.65	1.0	nC
Gate to Source Charge		Q _{GS}			0.07	0.10	nC
Gate to Drain Charge		Q _{GD}			0.31	0.5	nC
Gate Plateau Voltage		V _{plateau}			3.56		V
Turn-ON Delay Time		t _{D(ON)}	V _{DD} =300V, V _{GS} =10V, I _D =0.01A, R _G =6Ω		6.1	19.0	ns
Rise Time		t _R			9.7	14.5	ns
Turn-OFF Delay Time		t _{D(OFF)}			14	21	ns
Fall-Time		t _F			115	170	ns
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS							
Maximum Continuous Drain-Source Diode Forward Current		I _S	T _A =25°C			0.016	A
Maximum Pulsed Drain-Source Diode Forward Current		I _{SM}	T _A =25°C			0.09	A
Drain-Source Diode Forward Voltage		V _{SD}	I _F =0.016A, V _{GS} =0V, T _J =25°C		0.82	1.2	V
Body Diode Reverse Recovery Time		t _{rr}	V _R =300V, I _F =0.016A,		160	240	ns
Body Diode Reverse Recovery Charge		Q _{rr}	dl _F /dt=100A/μs		13.2	19.8	μC

Notes: 1. The Power Dissipation of the package may result in a lower continuous drain current.
2. Pulse Test: Pulse Width ≤ 300μs, Duty Cycle ≤ 2.0%.

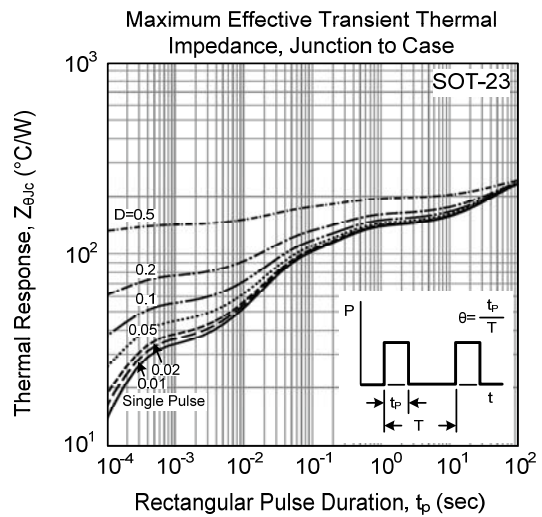
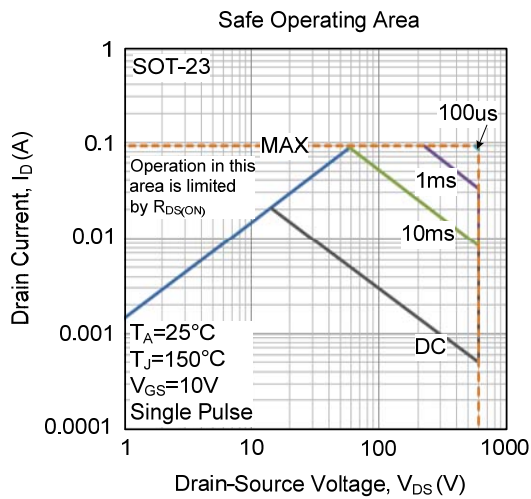
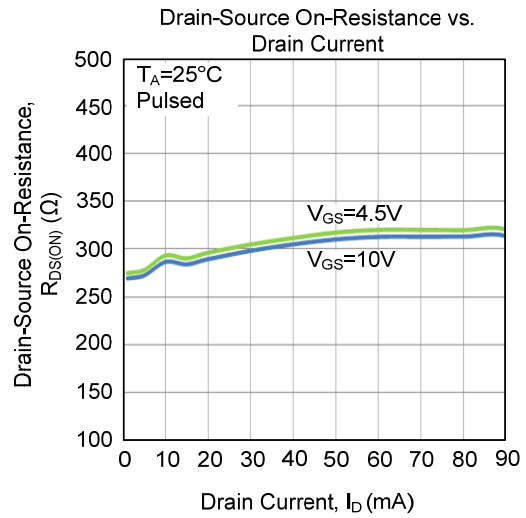
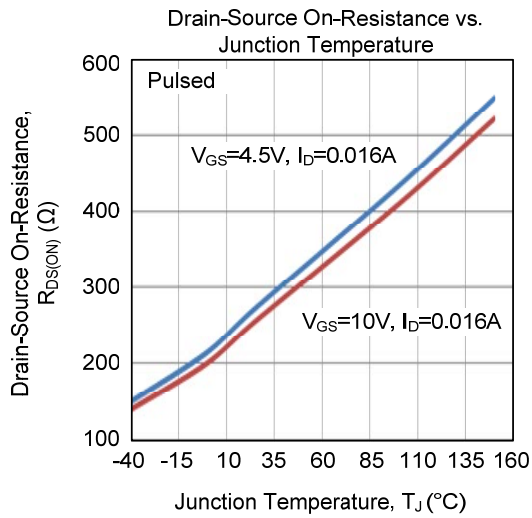
■ TEST CIRCUITS AND WAVEFORMS

Gate Charge Waveforms

■ TYPICAL CHARACTERISTICS



■ TYPICAL CHARACTERISTICS (Cont.)



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